TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT   SILICON MONOLITHIC
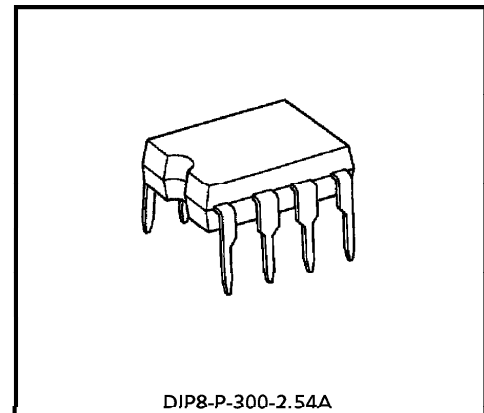
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SINGLE OPERATIONAL AMPLIFIER

The TA75060P is a J-FET input low-power operational amplifier with low input bias and offset current, fast slew rate. The TA75060P is pin compatible with the TA7506P. The TA75060P is an excellent choice for active filters, integrators, buffers and sample-and-hold circuits.
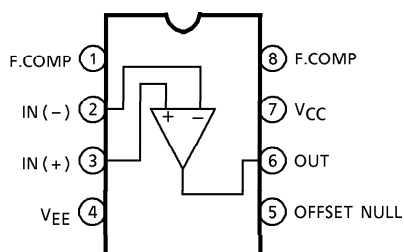

DIP8-P-300-2.54A

Weight : 0.5g (Typ.)

FEATURES

● Low Supply Current   : 250μA MAX.

● Low Input Bias Current   : 400pA MAX.

● Low Input Offset Current : 200pA MAX.

● High Slew Rate   : 3.5V / μs (A$_V$ = 1)

● Wide Supply Voltage Range : ±2~±18V

● Output Short Circuit Protection

● Offset Null Capability

PIN CONNECTION (TOP VIEW)

F.COMP ①   ⑧ F.COMP

IN (−) ②   ⑦ V$_{CC}$

IN (+) ③   ⑥ OUT

V$_{EE}$ ④   ⑤ OFFSET NULL

961001EBA1

EQUIVALENT CIRCUIT

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V_{CC}	18	V
	V_{EE}	− 18	V
Differential Input Voltage	DV_{IN}	± 30	V
Input Voltage	V_{IN}	± 15	V
Power Dissipation	P_D	500	mW
Operating Temperature	T_{opr}	− 40~85	°C
Storage Temperature	T_{stg}	− 55~125	°C

ELECTRICAL CHARACTERISTICS (V_{CC} = 15V, V_{EE} = − 15V, Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CIRCUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	V_{IO}	—	$R_g \le 10k\Omega$	—	3	15	mV
TC Of Input Offset Voltage	TCV_{IO}	—	—	—	10	—	$\mu V/°C$
Input Offset Current	I_{IO}	—	—	—	5	200	pA
Input Bias Current	I_I	—	—	—	30	400	pA
Common Mode Input Voltage	CMV_{IN}	—	—	± 11.5	± 12	—	V
Maximum Output Voltage	V_{OM}	—	$R_L = 10k\Omega$	20	27	—	V_{p-p}
Voltage Gain (Open Loop)	G_V	—	$V_{OUT} = \pm 10V$, $R_L = 10k\Omega$	3	6	—	V / mV
Unity Gain Cross Frequency	f_T	—	Open Loop, $R_L = 10k\Omega$	—	1	—	MHz
Input Resistance	R_{IN}	—	—	—	10^{12}	—	Ω
Common Mode Input Signal Rejection Ratio	CMRR	—	$R_g \le 10k\Omega$	70	76	—	dB
Supply Voltage Rejection Ratio	SVRR	—	$R_g \le 10k\Omega$	70	76	—	dB
Supply Current	I_{CC}, I_{EE}	—	Non load	—	200	250	μA

OPERATING CHARACTERISTICS (V_{CC} = 15V, V_{EE} = − 15V, Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CIRCUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Slew Rate	SR	—	$V_{IN} = 10V_{p-p}$, $R_L = 10k\Omega$, $C_L = 100pF$, $A_V = 1$	—	3.5	—	$V/\mu s$
Equivalent Input Noise Voltage	V_{NI}	—	$R_S = 100\Omega$, f = 1kHz	—	42	—	$nV/\sqrt{Hz}$

TYPICAL APPLICATION

(1) UNITY-GAIN BUFFER

10pF

(2) OFFSET NULL CIRCUIT

V_{CC}

20MΩ

1MΩ

C_C

(3) FEED FORWARD COMPENSATION

C_2

R_2

C_1

R_1

$$C_1 = 500pF$$
$$C_2 = \frac{1}{2\pi f_o R_2}$$
$$f_o \simeq 1MHz$$

(4) TOW POLE COMPENSATION

R_2

R_1

C_1
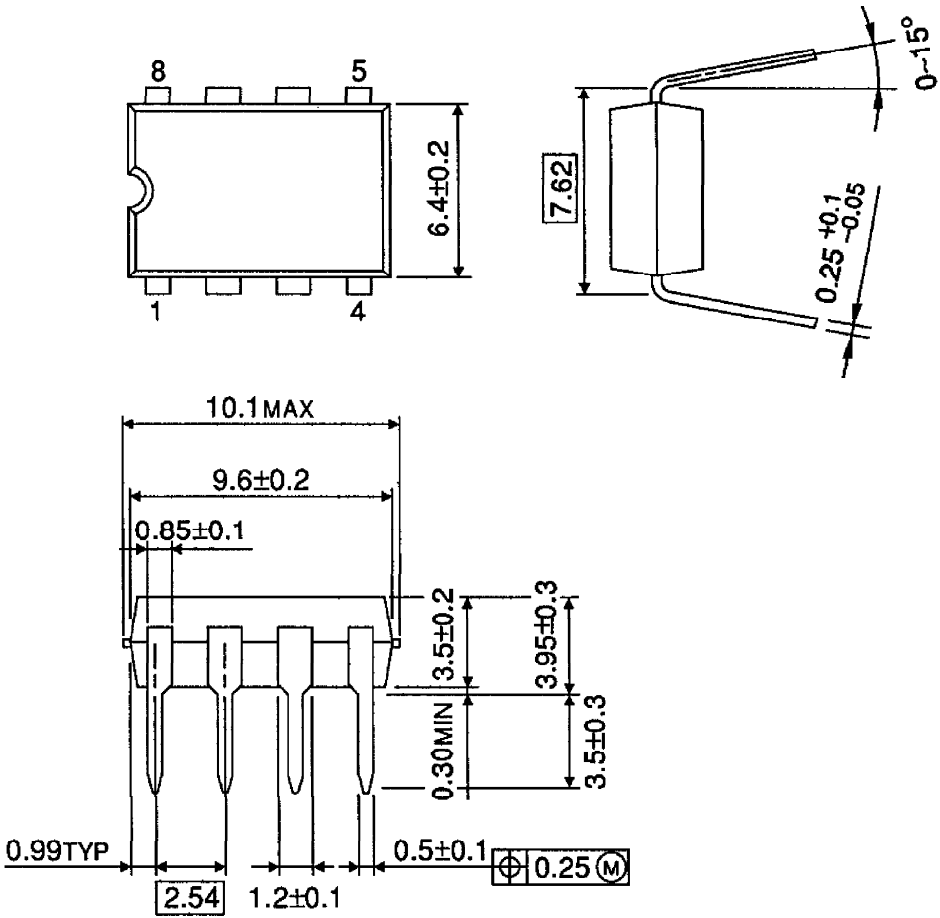
C_2

50kΩ

$$C_1 > \frac{R_1}{R_1 + R_2} C_S$$
$$C_S = 10pF$$
$$C_2 = 10C_1$$

OUTLINE DRAWING

DIP8-P-300-2.54A   Unit : mm

Weight : 0.5g (Typ.)